
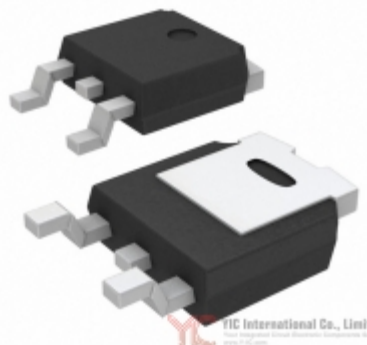



| | | |
|---|---|------------------------------------|
|  | <h2>STD6NK50ZT4</h2> | |
| | Hersteller-Teilenummer: | STD6NK50ZT4 |
|  | Hersteller / Marke: | STMicroelectronics |
| | Teil der Beschreibung: | MOSFET N-CH 500V 5.6A DPAK |
| Datenblätter: |  STD6NK50ZT4.pdf | |
| RoHs Status: | Bleifrei / RoHS-konform | |
| Lagerzustand: | New original, 33132 pcs Stock Available. | |
| Liefern von: | Hong Kong | |
| Versandweg: | DHL/Fedex/TNT/UPS/EMS | |
| Image may be representation. See specs for product details. | | |

Spezifikationen

| | |
|---|---|
| Teilenummer | STD6NK50ZT4 |
| Hersteller | STMicroelectronics |
| Beschreibung | MOSFET N-CH 500V 5.6A DPAK |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 33132 pcs Stock |
| Serie | SuperMESH™ |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | TO-252-3, DPak (2 Leads + Tab), SC-63 |
| Supplier Device-Gehäuse | D-Pak |
| Verlustleistung (max) | 90W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 500V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 °C | 5.6A (Tc) |
| Rds On (Max) @ Id, Vgs | 1.2 Ohm @ 2.8A, 10V |
| VGS (th) (Max) @ Id | 4.5V @ 50µA |
| Gate Charge (Qg) (Max) @ Vgs | 24.6nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 690pF @ 25V |
| Antriebsspannung (Max Rds On, Min Rds On) | 10V |
| Vgs (Max) | ±30V |
| Verpackung | Tape & Reel (TR) |

STD6NK50ZT4 ist neu im Original, Suche STD6NK50ZT4 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie STD6NK50ZT4 STMicroelectronics mit Garantie und Vertrauen. Anfrage STD6NK50ZT4: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|--|--|--|
|  STD70GK08 Sirectifier IGBT Modules |  STD6NF10 ST STD6NF10 ST |  STD6N95K5 STMicroelectronics MOSFET N-CH 950V 9A DPAK |  STD6N90K5 STMicroelectronics N-CHANNEL 900 V, 2.1 OHM TYP., 3 |
|  STD6NF10-1 VBsemi STD6NF10-1 VBsemi |  STD6NF10T4 STMicroelectronics MOSFET N-CH 100V 6A DPAK |  STD6NM60-1 ST STD6NM60-1 ST |  STD6NM60N STMicroelectronics MOSFET N-CH 600V 4.6A DPAK |

heiße Teile

Mehr

| | | | | |
|----------------|-----------------|-----------------|----------------|----------------|
| ⊕ STD60NF3LL-1 | ↔ STD60NF3LLT4 | ⇒ STD60NF55 | D STD60NF55L | ⇒ STD60NF55L-1 |
| ⊖ STD60NF55LA | ⊕ STD60NF55LAT4 | D STD60NF55LAT4 | ⇒ STD60NF55LT4 | ⇒ STD60NH03LT4 |
| ⊕ STD616A-1 | ⊖ STD616AT4 | ⊕ STD64N4F6AG | ↔ STD65N3LLH5 | ⇒ STD65N55F3 |
| D STD65N55LF3 | ⊕ STD65N55T4 | ⊖ STD65N6F3 | ⊕ STD65NF06 | ⇒ STD6N10T4 |
| ⇒ STD6N52K3 | ↔ STD6N62K3 | ⊕ STD6NF10 | ⊖ STD6NF10-1 | ⇒ STD6NF10T4 |
| ↔ STD6NM60N | ⇒ STD6NM60N-1 | D STD70GK08 | ⊕ STD70GK08B | ⊖ STD70GK12 |
| ⊕ STD70GK12B | D STD70GK14 | ⇒ STD70GK14B | ↔ STD70GK16 | ⇒ STD70GK16B |
| ⊖ STD70GK18 | ⊕ STD70GK18B | ↔ STD70N02 | ⇒ STD70N02L | ⇒ STD70N02L-1 |
| ⊕ STD70N02LH5 | ⊖ STD70N03L | ⊕ STD70N03LT4 | D STD70N10F4 | ⇒ STD70N2LH5 |
| ↔ STD70N6F3 | ⊕ STD70NH02L | ⊖ STD70NH02LT4 | ⊕ STD70NS04ZL | ⇒ STD75N3LLH6 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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